NSN 5962-01-361-6518

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Body Length: 1.490 inches

Hardened



View Online at https://aerobasegroup.com/nsn/5962-01-361-6518

Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.217 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
B-2
Features Provided:
Hermetically sealed and burn in and monolithic and positive outputs
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.0 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
6.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Eeprom
Special Features:
Nuclear hardness critical item
Nuclear Hardness Critical Feature:

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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